

SPST Wide Bandwidth Analog Switch

Features

- CMOS Technology for Bus and Analog Applications
- Low On-Resistance: 8Ω at 3.0V
- Wide V_{CC} Range: 1.65V to 6.0V
- Rail-to-Rail Signal Range
- Control Input Overvoltage Tolerance: 6.0V
- Fast Transition Speed: 2ns at 5.0V
- High Off Isolation: -63dB @ 10MHz
- I/O pins Have Power-off Protection Function
- Break-Before-Make Switching
- Extended Industrial Temperature Range: -40 °C to 85 °C
- Packaging (Pb-free & Green):
-5-pin SC70

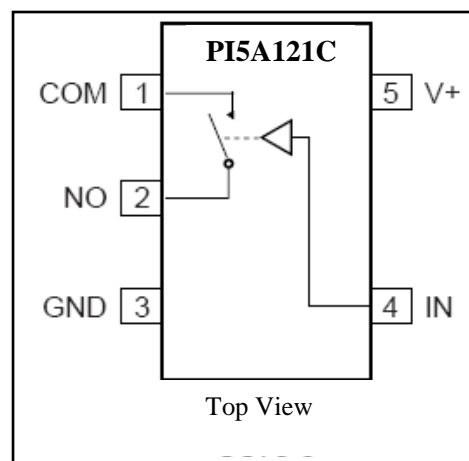
Applications

- Audio, Video Switching, and Routing
- Cell Phones
- PDAs
- Telecommunications
- Portable Instrumentation
- Battery powered Communication Systems
- Computer Peripherals
- Mechanical Relay Replacement

Description

The PI5A121C is a single-pole single throw (SPST) normally open (NO) CMOS switch. The switch is open when IN is LOW. The high-precision device is ideal for low-distortion audio, video, signal switching and routing. Specified over a wide operating power supply voltage, 1.65V to 6.0V, the PI5A121C has on-resistance of 12-ohms at 1.65V, 9-ohms at 2.3V & 6-ohms at 4.5V. The control input, IN, is independent of supply voltage.

Pin Assignment



Pin Description

Pin No	Pin Name	Description
1	COM	Common Output/Data Port
2	NO	Data Port
3	GND	Ground
4	IN	Logic Control
5	V+	Positive Power Supply

Logic Function Table

Logic Inputs(IN)	Function
0	OFF
1	ON

Maximum Ratings

Storage Temperature.....	-65°C to +150°C
Ambient Temperature with Power Applied.....	-40°C to +85°C
Supply Voltage V ₊	-0.3V to +7.0V
DC Control Voltage V _{IN}	-0.5V to 7.0V
DC Input Voltage (V _{NO} , V _{COM}).....	-0.3V to V ₊ + 0.5V
DC Output Current I _{OUT}	128mA
DC V ₊ or Ground Current I ₊ /I _{GND}	±100mA
Junction Temperature under Bias (T _J)	150 °C
Junction Lead Temperature (T _L) (Soldering, 10 seconds)	260 °C
Power Dissipation (P _d) @ +85 °C	180mW
ESD (HBM).....	2000V

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V ₊	Operating Voltage	-	1.65	-	6.0	V
V _{IN}	Control Input Voltage	-	0	-	6.0	V
V _{INPUT}	Switch Input Voltage	-	0	-	V ₊	V
V _{OUT}	Output Voltage	-	0	-	V ₊	V
T _A	Operating Temperature	-	-40	25	85	°C
t _r , t _f	Control Input Rise and Fall Time	V ₊ = 2.3V to 3.6V	0	-	10	ns/V
		V ₊ = 4.5V to 6.0V	0	-	5	ns/V

Note: Control input must be held HIGH or LOW; it must not float.

DC Electrical Characteristics

 (T_A = -40 °C to 85 °C, unless otherwise noted.)

Parameter	Description	Test Conditions	Temperature	Min	Typ	Max	Units	
V _{IAR}	Analog Input Signal Range	V+	-40 °C to 85 °C	0	-	6	V	
R _{ON}	ON Resistance ⁽¹⁾	V+=4.5V, I _O = 30mA, V _{INPUT} = 0V	25 °C	-	4	6	Ω	
		V+=4.5V, I _O = -30mA, V _{INPUT} = 2.4V		-	5	8		
		V+=4.5V, I _O = -30mA, V _{INPUT} = 4.5V		-	7	11		
		V+=4.5V, I _O = 30mA, V _{INPUT} = 0V	-40 °C to 85 °C	-	-	6		
		V+=4.5V, I _O = -30mA, V _{INPUT} = 2.4V		-	-	8		
		V+=4.5V, I _O = -30mA, V _{INPUT} = 4.5V		-	-	11		
		V+=3.0V, I _O = 24mA, V _{INPUT} = 0V	25 °C	-	5	8		
		V+=3.0V, I _O = -24mA, V _{INPUT} = 3.0V		-	10	15		
		V+=3.0V, I _O = 24mA, V _{INPUT} = 0V		-	-	8		
		V+=3.0V, I _O = -24mA, V _{INPUT} = 3.0V	-40 °C to 85 °C	-	-	15		
		V+=2.3V, I _O = 8mA, V _{INPUT} = 0V		-	6	9		
		V+=2.3V, I _O = -8mA, V _{INPUT} = 2.3V		-	13	20		
		V+=2.3V, I _O = 8mA, V _{INPUT} = 0V	25 °C	-	-	9		
		V+=2.3V, I _O = -8mA, V _{INPUT} = 2.3V		-	-	20		
		V+=2.3V, I _O = 8mA, V _{INPUT} = 0V		-	-	9		
		V+=2.3V, I _O = -8mA, V _{INPUT} = 2.3V	-40 °C to 85 °C	-	-	20		
		V+=1.65V, I _O = 4mA, V _{INPUT} = 0V		-	8	12		
		V+=1.65V, I _O = -4mA, V _{INPUT} = 1.65V		-	20	30		
V+=1.65V, I _O = 4mA, V _{INPUT} = 0V	25 °C	-	-	12				
V+=1.65V, I _O = -4mA, V _{INPUT} = 1.65V		-	-	30				
V+=1.65V, I _O = 4mA, V _{INPUT} = 0V		-	-	12				
V+=1.65V, I _O = -4mA, V _{INPUT} = 1.65V	-40 °C to 85 °C	-	-	30				
R _{ONF}		ON Resistance ^(1,2,3) Flatness	V+=5.0V, I _A = -30mA, 0 ≤ V _{INPUT} ≤ V+	25 °C	-	6	-	Ω
			V+=3.3V, I _A = -24mA, 0 ≤ V _{INPUT} ≤ V+		-	12	-	
	V+=2.5V, I _A = -8mA, 0 ≤ V _{INPUT} ≤ V+		-		22	-		
	V+=1.8V, I _A = -4mA, 0 ≤ V _{INPUT} ≤ V+		-		90	-		
V _{IH}	Input High Voltage (Logic High Level)	V+=1.65V	-40 °C to 85 °C	1	-	-	V	
		V+ = 2.3V		1.2	-	-		
		V+ = 3V		1.3	-	-		
		V+ = 4.2V		1.5	-	-		
		V+ = 6.0V		1.8	-	-		
V _{IL}	Input Low Voltage (Logic Low Level)	V+=1.65V	-40 °C to 85 °C	-	-	0.4	V	
		V+ = 2.3V		-	-	0.6		
		V+ = 3V		-	-	0.8		
		V+ = 4.2V		-	-	1		
		V+ = 6.0V		-	-	1.2		
I _{LKC}	Logic Input Leakage Current	0 ≤ V _{IN} ≤ 6.0V, V+ = 0V to 6.0V	25 °C	-	-	±0.1	μA	
			-40 °C to 85 °C	-	-	±1.0		
I _{OFF}	OFF State Leakage Current	0 ≤ V _{INPUT} ≤ V+, V+ = 1.65V to 6.0V	25 °C	-	-	±0.1	μA	
			-40 °C to 85 °C	-	-	±10		
I _{PWROFF}	Input Leakage Current for Power off	0 ≤ V _{INPUT} ≤ 6.0V, V+ = 0V	25 °C	-	-	±1	μA	
			-40 °C to 85 °C	-	-	±5		
I+	Quiescent Supply Current	All channels ON or OFF, V _{IN} = V+ or GND, I _{OUT} = 0, V+ = 6.0V	25 °C	-	-	1	μA	
			-40 °C to 85 °C	-	-	5		

Notes:

1. Measured by voltage drop between COM and NO pins at the indicated current through the device. ON resistance is determined by the lower of the voltages on two ports (COM or NO).
2. Parameter is characterized but not tested in production.
3. Flatness is defined as difference between maximum and minimum value of ON resistance over the specified range of conditions. Guaranteed by design.

Capacitance⁽¹⁾
(T_A = 25 °C, unless otherwise noted.)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
C _{IN}	Control Input	V ₊ = 5.0V, f = 1 MHz ⁽¹⁾	-	2.5	-	pF
C _{OFF}	NO Port, Switch OFF		-	5.0	-	
C _{COM ON}	COM Port, Switch ON		-	15.0	-	

Notes:

1. Capacitance is characterized but not tested in production

Switch and AC Characteristics⁽¹⁾

Parameter	Description	Test Conditions	Supply Voltage	Temperature	Min	Typ	Max	Units
t _{ON}	Turn-On Time	R _L =100Ω, C _L =35pF, See Test Circuit Figure 1.	V ₊ = 3.3V, V _{NO} =3.0V, V _{IH} =3.0V,	-40~+85 °C	-	3.6	6	
			V ₊ = 5.0V, V _{NO} =3V, V _{IL} =3V,		-	3	5	
t _{OFF}	Turn-Off Time	R _L =100Ω, C _L =35pF, See Test Circuit Figure 1.	V ₊ = 3.3V, V _{NO} =3.0V, V _{IH} =3.0V,	-40~+85 °C	-	3	5	ns
			V ₊ = 5.0V, V _{NO} =3V, V _{IL} =3V,		-	2.5	4	
Q	Charge Injection	C _L = 1nF, V _{GEN} = 0V, R _{GEN} =0Ω. See Test Circuit Figure 2.	V ₊ = 5.0V	+25 °C	-	5	-	pC
			V ₊ = 3.3V		-	4	-	
OIRR	Off Isolation	R _L =50Ω, V _{GEN} =0V, R _{GEN} =0Ω, f = 10MHz.	V ₊ = 1.65V to 5.5V	25 °C	-	-63	-	db
f _{3dB}	-3dB Bandwidth	See Test Circuit Figure 5.	V ₊ = 1.65V to 5.5V	+25 °C	-	500	-	MHz

Notes:

1. Guaranteed by design.

Test Circuits and Timing Diagrams

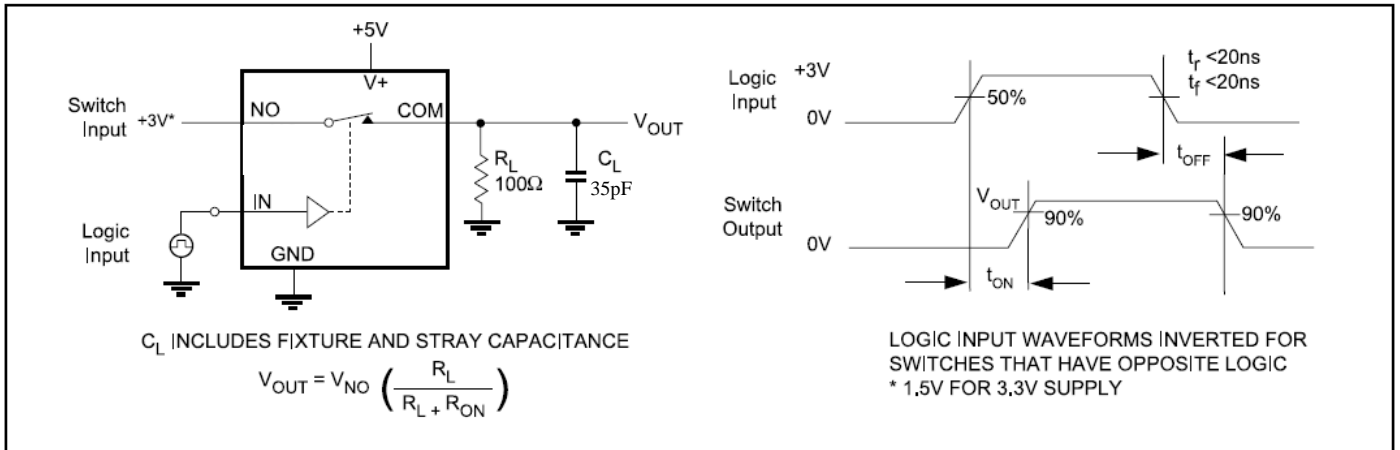


Figure 1. Switching Time

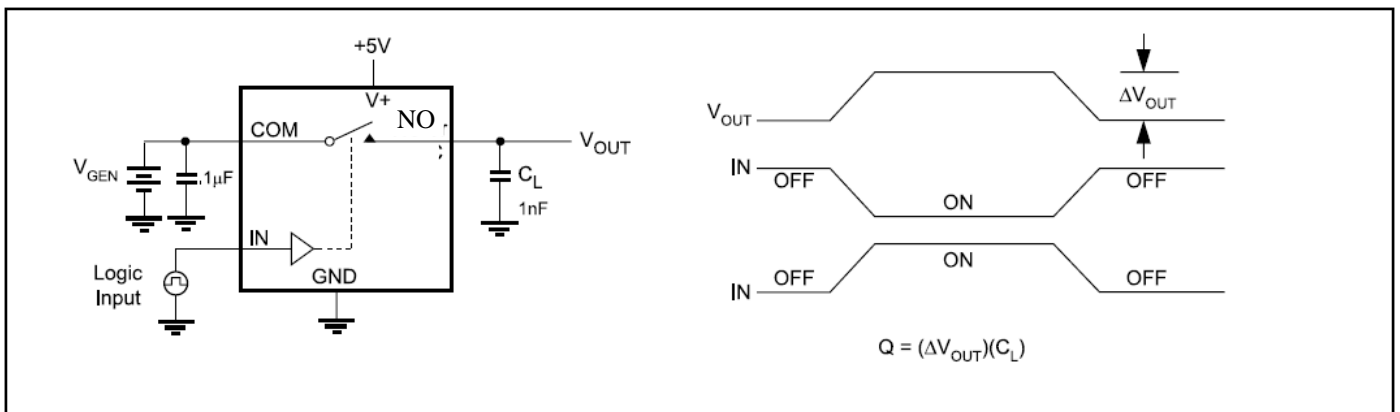


Figure 2. Charge Injection

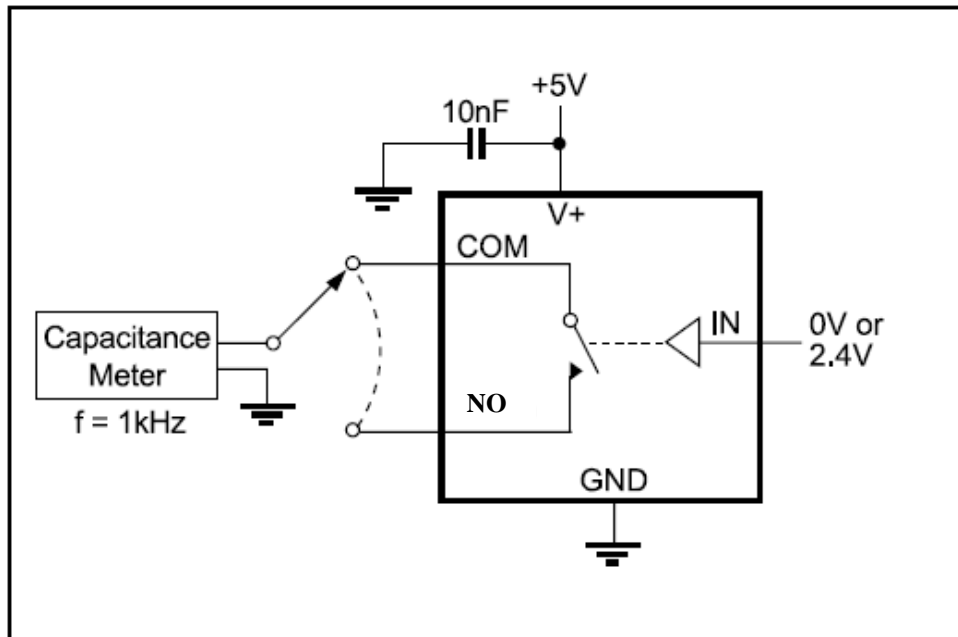


Figure 3. Channel-Off Capacitance

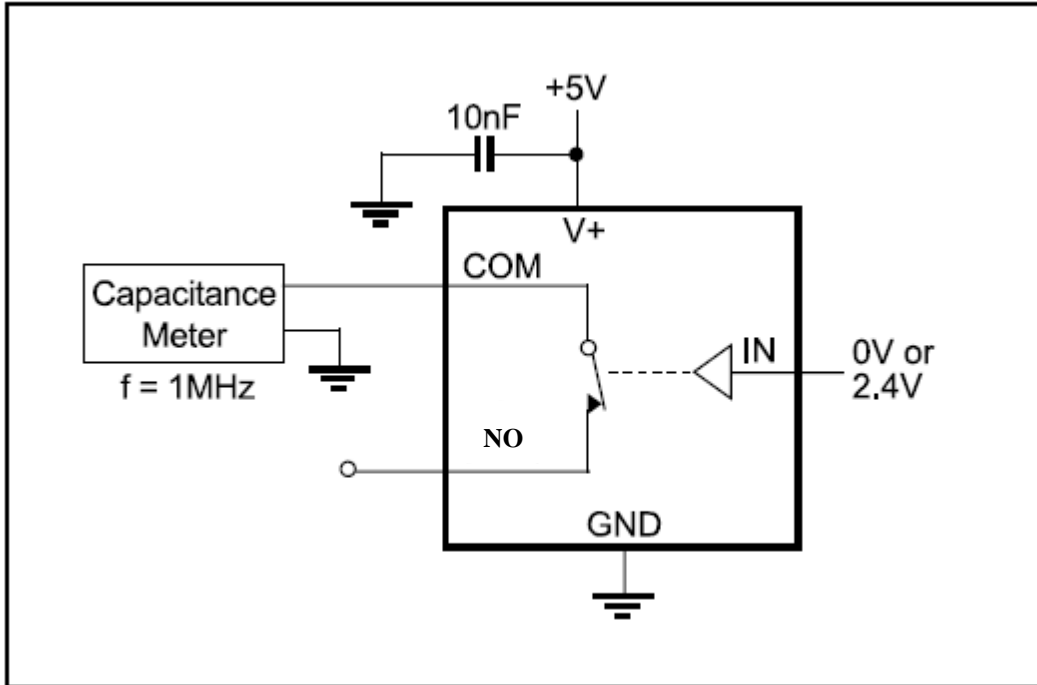


Figure 4. Channel-On Capacitance

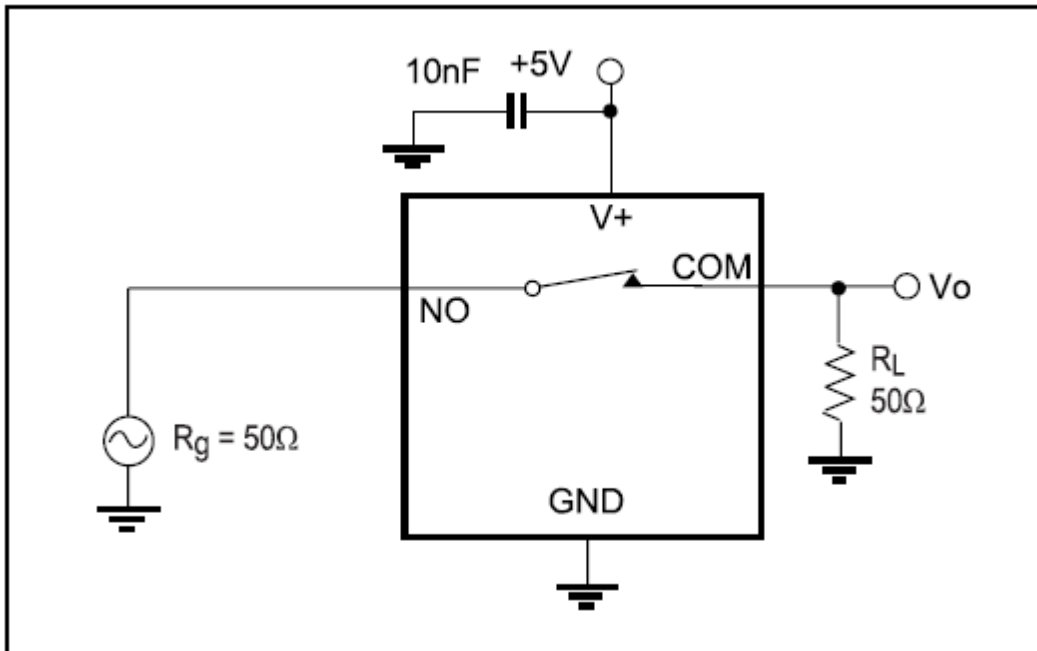
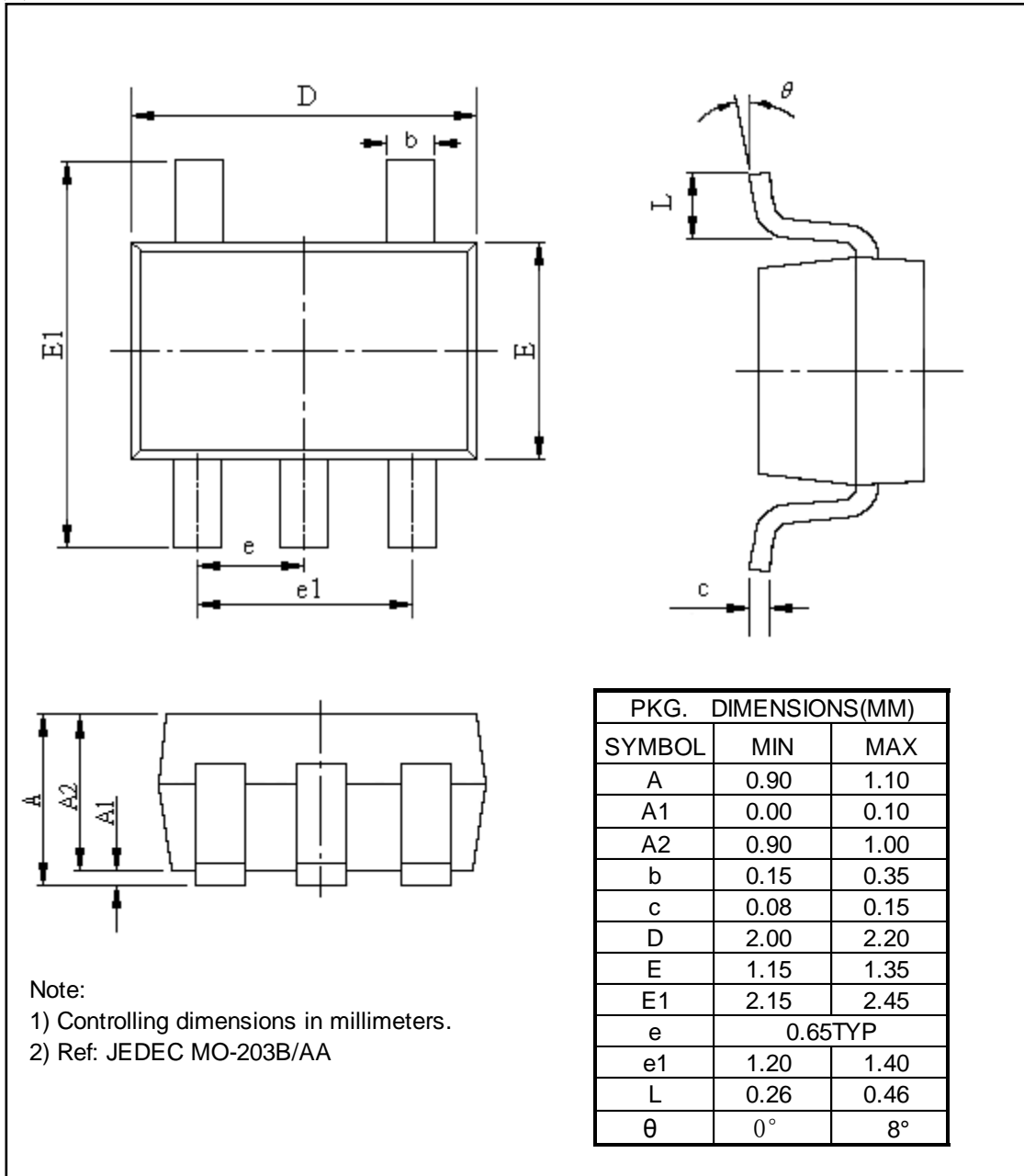


Figure 5. Bandwidth

Mechanical Information

5-pin SC70 (C)



Ordering Information

Part Number	Package Code	Package	Top Marking
PI5A121CCE	C	Lead Free and Green SC70-5 (C)	rD

Notes:

- E = Pb-free and Green
- Adding X Suffix= Tape/Reel

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